

Supporting Information for Characterization of [1]Ben- zothieno[3,2-*b*]benzothiophene (BTBT)-Derivatives with End- Capping Group as Solution-Processable Organic Semiconduc- tors for Organic Field-Effect Transistors

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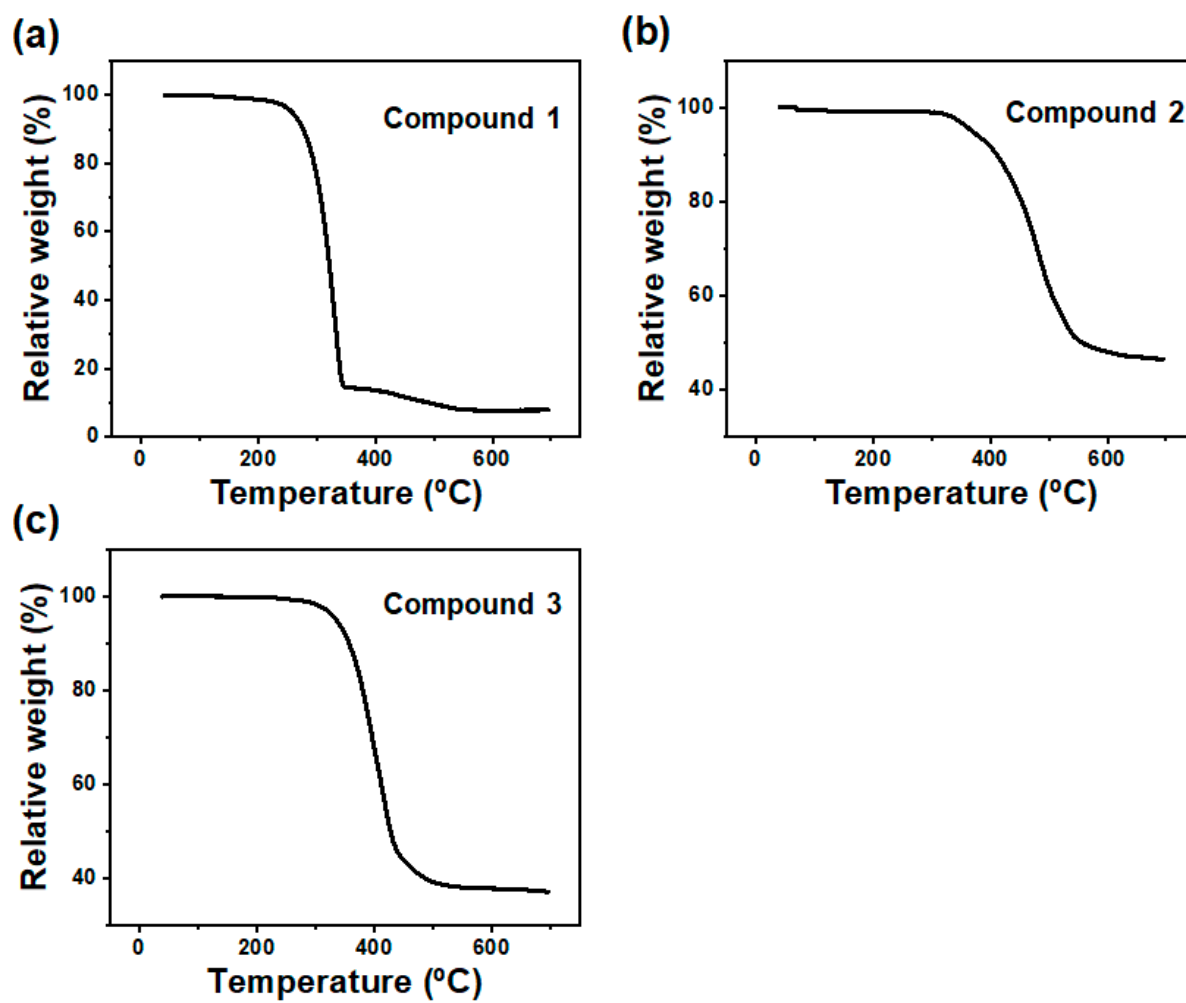


Figure S1. Thermogravimetric analysis (TGA) of BTBT-derivatives, (a) compound 1, (b) compound 2, and (c) compound 3.

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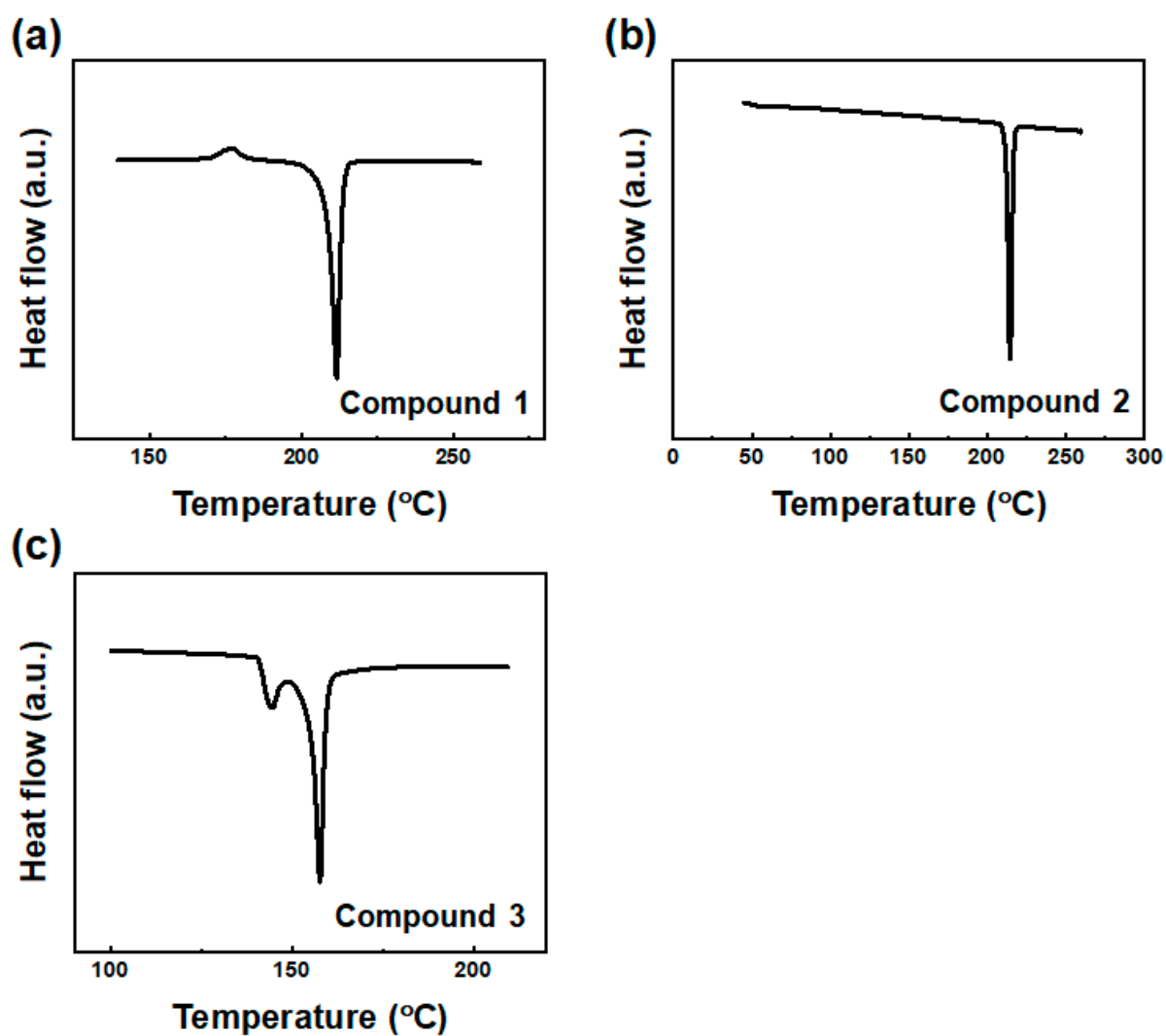


Figure S2. Differential scanning calorimetry (DSC) analysis of BTBT-derivatives, (a) compound 1, (b) compound 2, and (c) compound 3.

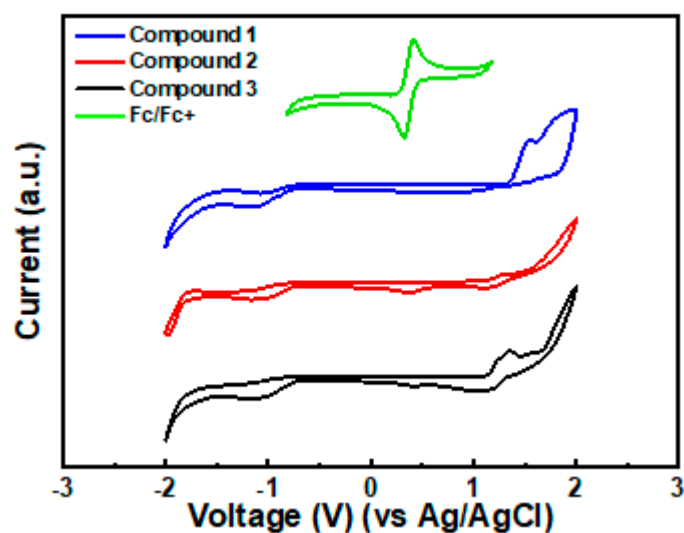


Figure S3. Cyclic voltammograms of compounds 1 – 3.

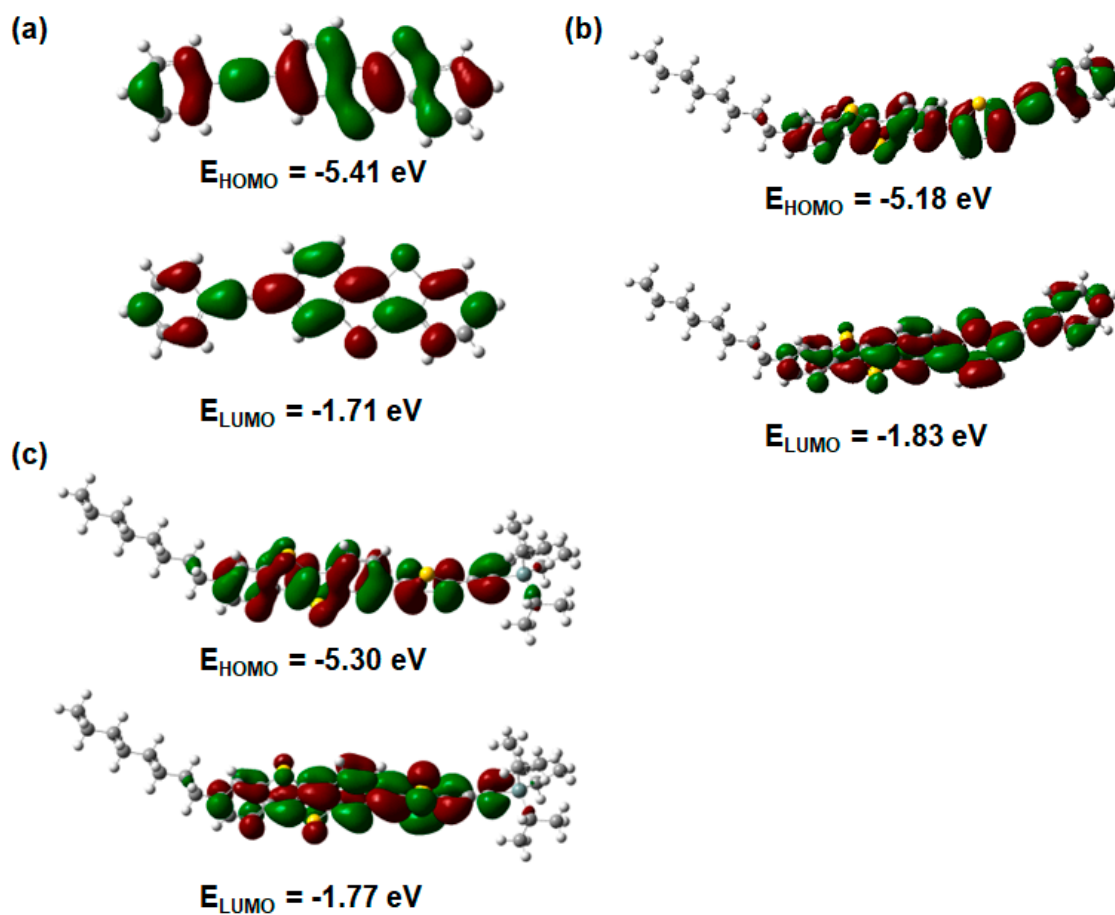


Figure S4. Molecular orbital surfaces of HOMO and LUMO by DFT calculation of compounds (a) 1, (b) 2, and (c) 3.

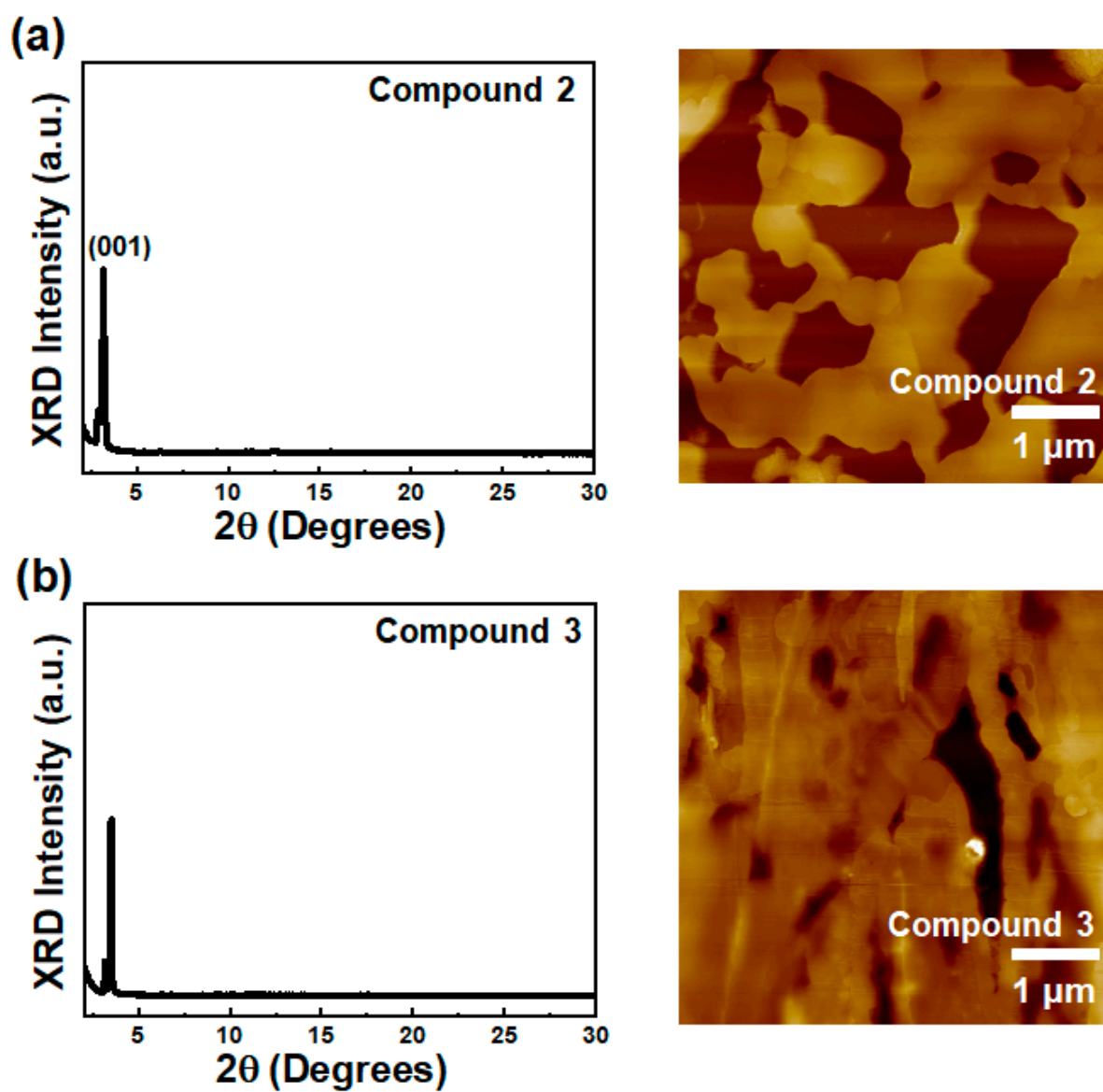


Figure S5. XRD profiles and AFM topographic images of solution-sheared film for (a) compound 2 and (b) compound 3.

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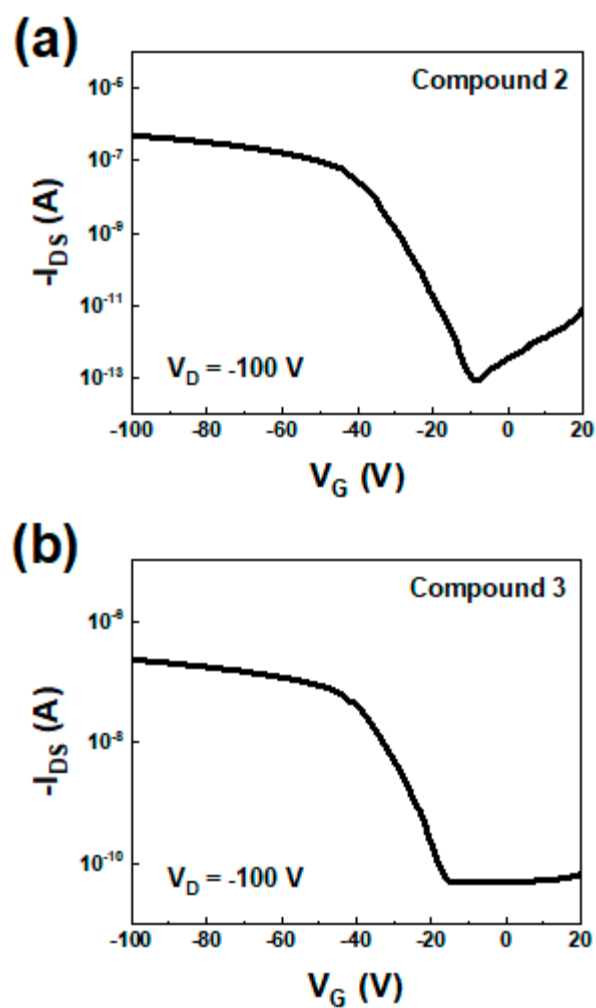


Figure S6. Representative transfer characteristics of OFETs based on (a) compound 2 and (b) compound 3.

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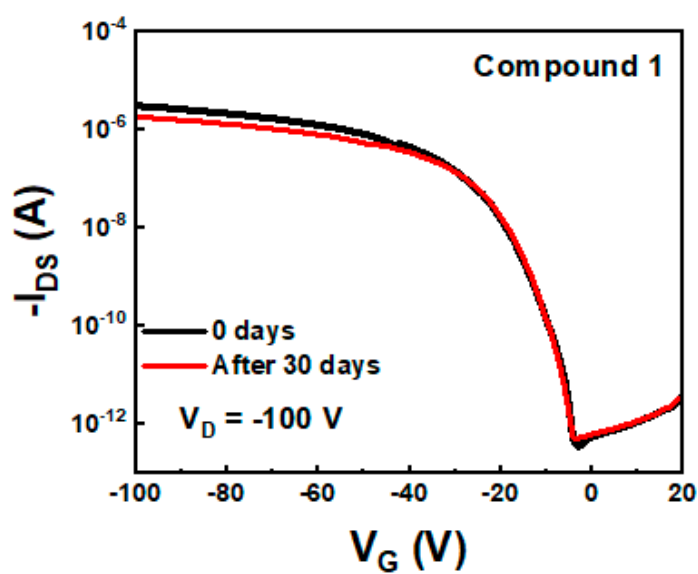


Figure S7. Transfer curve of OFETs based on compound 1 after 30 days of device fabrication.

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